Dual General Purpose Transistors

NPN Duals

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-363/SC-88 which is designed for low power surface mount applications.

Features

• Pb–Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	BC846	BC847	BC848	Unit
Collector-Emitter Voltage	V _{CEO}	65	45	30	V
Collector-Base Voltage	V _{CBO}	80	50	30	V
Emitter-Base Voltage	V _{EBO}	6.0	6.0	5.0	V
Collector Current – Continuous	Ι _C	100	100	100	mAdc

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

Symbol	Мах	Unit			
P _D	380 250	mW			
	3.0	mW/°C			
R_{\thetaJA}	328	°C/W			
T _J , T _{stg}	-55 to +150	°C			
	P _D	P _D 380 250 3.0 R _{θJA} 328			

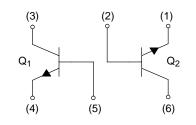
THERMAL CHARACTERISTICS

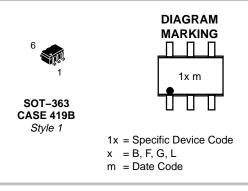
1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in



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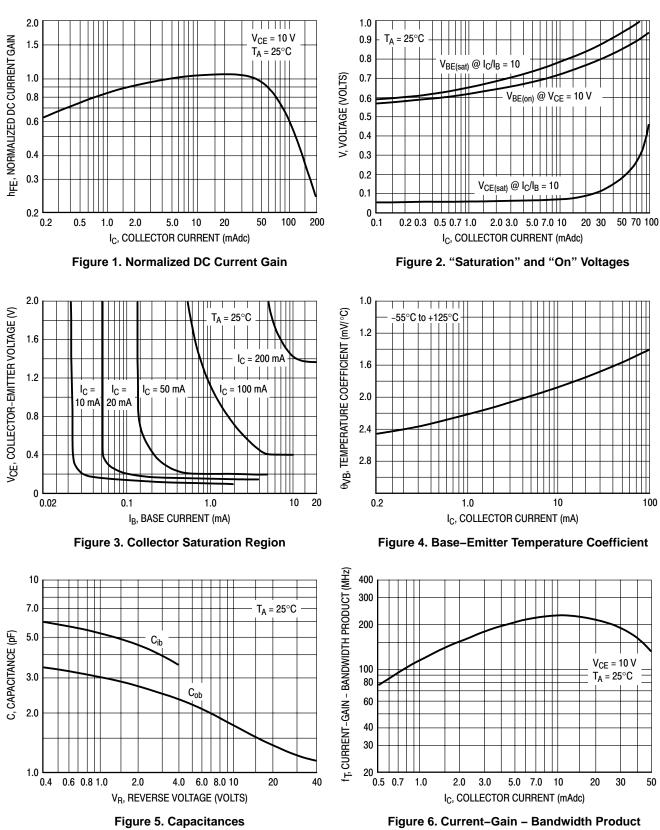


ORDERING INFORMATION

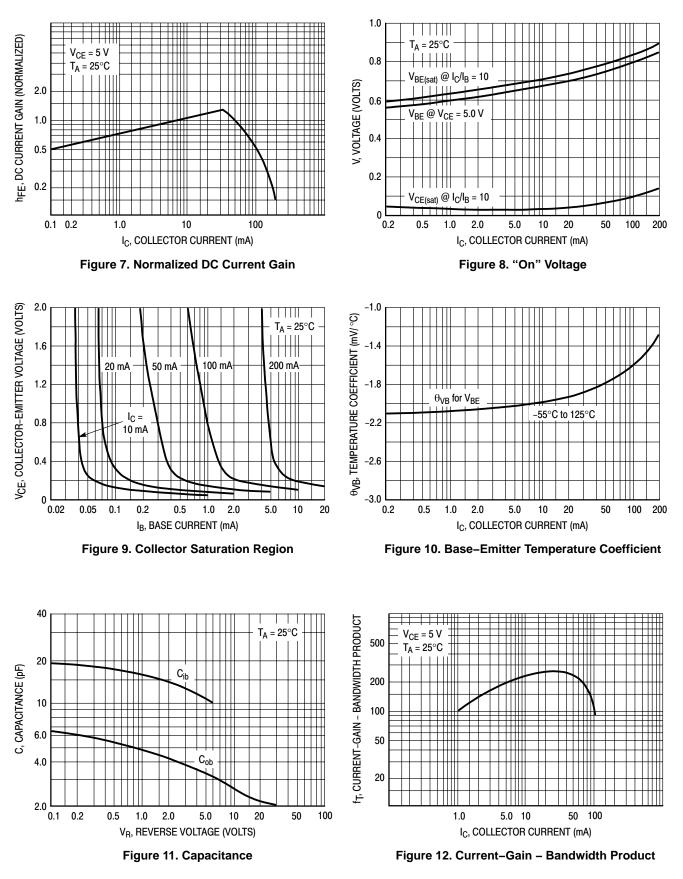
See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Characteristic		Min	Тур	Мах	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (I _C = 10 mA) BC846 BC847 BC848	Series	65 45 30			V
	Series	80 50 30	- - -		V
$\begin{array}{c} \mbox{Collector}-\mbox{Base Breakdown Voltage} \\ (I_C = 10 \ \mu A) & BC846 \\ BC847 \\ BC848 \\ \end{array}$	Series	80 50 30	- - -	- - -	V
Emitter – Base Breakdown Voltage (I _E = 1.0 μ A) BC846 BC847 BC848	Series	6.0 6.0 5.0		- - -	V
Collector Cutoff Current (V _{CB} = 30 V) (V _{CB} = 30 V, T _A = 150°C)	I _{CBO}			15 5.0	nA μA
ON CHARACTERISTICS			I	I	1
	h _{FE}		150 270	- -	-
$(I_{C} = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$ BC846B, BC847B, BC847C, BC848C		200 420	290 520	450 800	
Collector – Emitter Saturation Voltage (I _C = 10 mA, I _B = 0.5 m, (I _C = 100 mA, I _B = 5.0 m	, = (,		_ _	0.25 0.6	V
Base – Emitter Saturation Voltage (I _C = 10 mA, I _B = 0.5 mA) (I _C = 100 mA, I _B = 5.0 mA)	V _{BE(sat)}		0.7 0.9	_ _	V
Base – Emitter Voltage (I _C = 2.0 mA, V _{CE} = 5.0 V) (I _C = 10 mA, V _{CE} = 5.0 V)	V _{BE(on)}	580 -	660 -	700 770	mV
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain – Bandwidth Product ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz}$)	f _T	100	-	_	MHz
Output Capacitance (V_{CB} = 10 V, f = 1.0 MHz)	C _{obo}	-	-	4.5	pF
Noise Figure (I _C = 0.2 mA, V _{CE} = 5.0 Vdc, R _S = 2.0 k Ω ,f = 1.0 kHz, BW =	= 200 Hz)	-	_	10	dB

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)



TYPICAL CHARACTERISTICS – BC846 SERIES



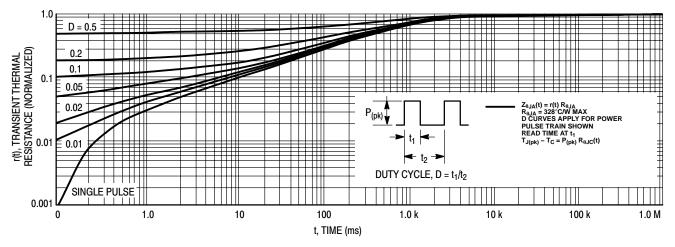


Figure 13. Thermal Response

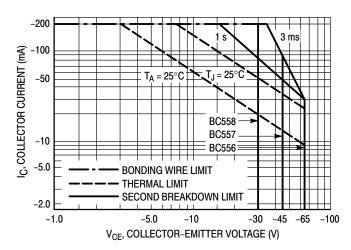


Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate I_C-V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon $T_{J(pk)} = 150^{\circ}$ C; T_{C} or T_{A} is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}$ C. $T_{J(pk)}$ may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

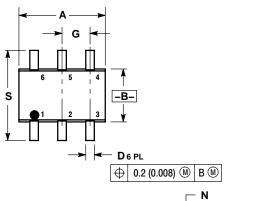
Device	Markings	Package	Shipping [†]
BC846BDW1T1		SOT-363	
BC846BDW1T1G	- 1B	SOT–363 (Pb–Free)	3000 Units/Reel
BC847BDW1T1	_	SOT-363	
BC847BDW1T1G	- 1F	SOT–363 (Pb–Free)	3000 Units/Reel
BC847BDW1T3	_	SOT-363	
BC847BDW1T3G	- 1F	SOT–363 (Pb–Free)	10000 Units/Reel
BC847CDW1T1	_	SOT-363	
BC847CDW1T1G	- 1G	SOT–363 (Pb–Free)	3000 Units/Reel
BC848CDW1T1		SOT-363	
BC848CDW1T1G	- 1L	SOT–363 (Pb–Free)	3000 Units/Reel

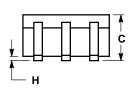
ORDERING INFORMATION

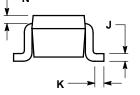
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SC-88 (SOT-363) CASE 419B-02 ISSUE T





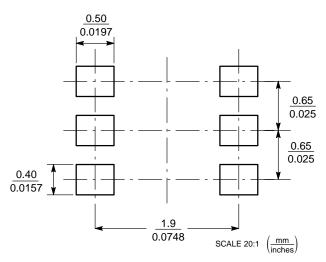


NOTES:
DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.
419B-01 OBSOLETE, NEW STANDARD 419B-02.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
С	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026 BSC		0.65 BSC		
н		0.004		0.10	
J	0.004	0.010	0.10	0.25	
К	0.004	0.012	0.10	0.30	
Ν	0.008 REF		0.20 REF		
S	0.079	0.087	2.00	2.20	



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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